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# Design, Analysis and Performance Evaluation of Electrical Power Subsystem Based on Triple-Junctions Solar PV Cells and SEPIC for a Conceptual 1u Cubesat Mission

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#### Abstract

This study aims to popularize low voltage power supply design especially for space satellite Cubesat mission and other portable consumer electronic devices. In this context, a preliminary design of an electrical power subsystem (EPS) is carried out for a conceptual 1u Cubesat mission in this paper. Mathematical modeling of the basic elements of the EPS is presented. Photovoltaic (PV) power generation system that is selected is made up of triple-junction solar cells, and the battery charging system based on lithium technology as well as the power conditioning converters are selected based on single ended primary inductance converter topology popularly abbreviated as SEPIC. Triple-junction solar PV cell results are verified by comparing with the datasheet values. A maximum power point tracking algorithm which is known as perturb and observe is implemented and proportional-integral controller is used for the SEPIC. All of these are well analyzed, mathematically modeled and simulated. Feasibility of the designed EPS is verified by comparing with similar devices from different manufacturers.

**Key Words:** Space technology, CubeSat, Electrical power subsystem, DC/DC power converters, Solar photovoltaic cells.

#### 1. INTRODUCTION

The space industry stakeholders need a very ideal electrical power subsystem (EPS) that can work perfectly well under constraints, if achievable, function beyond the mission duration. So far, only solar photovoltaic (PV) system can be employed for the power generation on a CubeSat looking at specifications and design guidelines given in [1]. This is especially required if the satellite is to operate in a region of space called the low earth orbit (LEO) since there are frequent eclipses on its path [2]. In

addition to solar PV system, load regulators (power conditioning and distribution) must be also included in the satellite system [1], [3], and [5]. In [2], the main objective of CubeSat program is given to provide opportunities especially for university students to test their designs and launch overheads particularly for experiments, other commercial and scientific demonstrations purposes. Advancement of a budget-constrained EPS would require that the design engineers develop custom or use commercial-off-the-shelf components like the solar PV cells, lithium based batteries and the other electronic components for the power supply. Appropriate design practice therefore is expected to be the order to ensure that the design complies with the requirements in [1]. According to the works presented in [1]-[5], the EPS contains the solar PV cells for generating power required, a series converter for maximum power point tracking (MPPT), a voltage regulator for power conditioning and a lithium battery storage unit.

The employment of PV cell in space satellites have directed the researchers to focus on the modeling, simulation and performance evaluation of relatively new technologies. Therefore, they need to verify the demands being reported by the manufacturers and design MPPT algorithms [6]-[8]. Hence, there is a requirement to design hardware that can extract the maximum power from PV cells at all times, that's why, it's necessary to carry out modeling of the PV cell with multi-junction solar cells [9]. Viability of CubeSat technology necessitates this approach since it has become popular over the years among scientists and other professional engineers.

The main purpose of this study is to design and simulate all the main building blocks of an EPS for a conceptual 1U CubeSat that can safely. effectively and continuously supply all its loads in LEO without any failure for the intended mission lifetime where it would be employed. Objective of concept is also to have a simple and cost effective EPS design that can be reused on any type of mission of its kind. When the study is briefly overviewed, the produced energy from PV cell must be controlled using DC/DC converter in order to provide a regulated voltage for Cubesat mission. Among the existing DC/DC converters in the literature, single ended primary inductance converter (SEPIC) topology that is controlled with PI controller is preferred for this application. Also, lithium technology is used for battery storage system. The overall designed EPS system is illustrated in Figure 1. In order to achieve the stated objectives above, the following tasks are conducted. A literature review presented in Table 1 on CubeSat projects and EPS designs of these projects are exhibited. Design of a skeletal and simple reusable CubeSat EPS that can be used in LEO missions or other uses in portable consumer electronics like mobile phones is achieved. A review on the available and most viable PV cells is also carried out and from among the bests, a choice is made based on heritage and reported performance of the cells. Most popular load voltage regulators and switched-mode power supplies for power conditioning and distribution are reviewed and a decision is taken on which one to employ in this application. A review with a view to considering the battery technologies and associated efficiencies available for space applications especially LEO is also attempted and the most suitable selected. Solar PV cells are mathematically modeled and simulated in simulation environment. 3.3 V and 5.0 V DC power supply and MPPT based battery charging converters are designed, modeled and simulated by using state-space averaging technique. A comparison is carried out with similar studies and effectiveness of designed concept is presented. The main contributions of this paper are briefly presented as in the followings. EPS based on triple-junctions solar PV cells and SEPIC is designed and mathematically analyzed, and verification of EPS is done in a comparative ways. The obtained results can be beneficial for power supply designers. In addition, space industry stakeholders can take the advantageous of the simulation results for space satellite Cubesat mission without necessarily having to carry out extensive literature review thanks to this study.

The organization of this paper is as follows. In Section II, the theory and mathematical modeling of triple-junction solar cell is introduced together with modeling and control of SEPIC. Section III presents the simulation results. Simulation validation is shown by comparing with datasheet of triple-junction PV cell at STC and, I-V and P-V characteristics of cell under various conditions are exhibited. Voltage and current output characteristics are given with satisfactory outcomes for 3.3V and 5V SEPIC, respectively. Evaluation of obtained results is discussed by verifying the superior performance of designed EPS in Section IV. Finally, Section V concludes this paper.

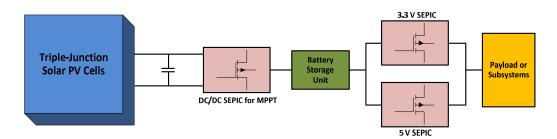


Figure 1. Schematic diagram of designed EPS system

**Table 1:** A review of some University CubeSat projects

Name	Owner	Туре	Solar Cell Technology	Battery Cell Technology	Architecture	Bus Voltages
NCube1	Norwegian University	1U	Not Sure	Not Sure	Not Sure	3.3V & 5.0V
DICE	Utah State University	1.5U	Triple Junction	Lithium – Polymer	Centralized & PPT	8.2V (Unregula ted), 5.0V and 3.3V
Name	Owners	Туре	Solar Cell Technology	Battery Cell Technology	Architecture	Bus Voltages
NUTS- NTNU	Norwegian University	2U	N/A	Lithium- ferrite	MPPT and Distributed	3.3V & 5.0V
Aalto – 1	Aalto University	3U	Triple Junction	Lithium Polymer cells	MPPT and Centralized	3.3V, 5.0V and 12V
Aalto – 2	Aalto University	2U	Triple Junction	Lithium-ion	MPPT and Centralized	3.3V and 5.0V
NMTSat	New Mexico Tech.	3U	Triple Junction	N/A	MPPT	3.3V and 5.0V
Concept ual Design	Islamic Azad University	Nano satell ite	Multi Junction	Lithium-ion battery	MPPT and Distributed	10.5V
TINYSC OPE	Naval Postgradua te School	5U or 6U	Advanced Triple Junction	Lithium-ion	Not sure	3.3V, 5.0V and 12V
CubeST AR	University of Oslo	2U	Multi Junction	LiFePO4 battery cell	MPPT and Distributed	3.3V and 5.0V
ESTCub e-1	University of Estonia	1U	N/A	Lithium-ion	MPPT and Distributed	N/A
ECOSat	University of Victoria	Not clear	Ultra-Triple Junction	Lithium-ion	DET Direct Energy Transfer	3.3V, 5.0V and 7.0V
CubeCa t-1	Universitat Politecnica du Catalunya	1U	N/A	N/A	MPPT and Distributed battery bus	3.3V and 5.0V
OUFTI- 1	University of Liege Belgium	1U	Triple Junction	Lithium Polymer	DET Direct Energy Transfer	3.3V, 5.0V and 7.2V
Goliath	University of Bucharest	1U	N/A	N/A	DET Centralize	3.3V, 5.0V
Explore r 1 [PRIME ]	Montana State University	1U	N/A	Lithium-ion	N/A	N/A
e-star	Politecnico di Torino Italy	1U	N/A	N/A	N/A	N/A
AAUSA T	Aalborg University	1U	N/A	Lithium-ion cells	MPPT	5.0 V
Kufasat	University of Kufa	1U	Hybrid AzurSpace TJ	Lithium Polymer batteries	MPPT	3.3V, 5.0V

NPSAT1	Naval Postgradua te School	1U	Improved Triple junction	Lithium Polymer batteries	MPPT Centralized	3.3V, 5.0V
FunCub e-1	AMSAT-UK	1U	Triple Junction	Lithium-ion GOMSpace Denmark	MPPT	3.3V and 5.0V
NANOS ATC- BR1	Federal University	1U	N/A	N/A	MPPT Distributed	3.3V and 5.0V

# 2. DESIGN, MODELING AND OPERATION OF ELECTRICAL POWER SUBSYSTEM

#### 2.1 Theory and Mathematical Modeling of Triple-Junction Solar Cell

Performance characteristics of a space grade PV triple-junction solar cell are successfully evaluated using a single-diode model equivalent circuit and analytical modeling in the literature. The theory and evolution of multijunction solar cell have been explained in detail in [10-13], while the methods of modeling of PV cells are given in [10-17].

The triple-junction solar cell is made as stack of three individual subcells having dissimilar parameters of decreasing energy band gap connected together in series with the sub-cell having the lowest band gap. This construction ensures a better absorption of the light spectrum reaching the cell. The triple-junction cell obtains its higher efficiency status to this method of production [10-17]. Fabrication methods of triple-junction solar cells are investigated in [10] and [13]. The solar PV cell is modeled as a current source with an anti-parallel diode to account for reverse saturation and sometimes these reverse saturation and recombination currents are lumped together. Two resistors, one in parallel with the diode(s) and the other in series with them are connected in the model. The one-diode model known as a 5-parameter model is addressed in [15] and [18].

Figure 2 shows a one-diode 5-parameter model for a single junction cell whereas three of such cells are connected together to obtain triple-junction solar cell as indicated in Figure 3.

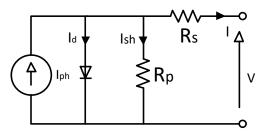


Figure 2. A Generic one-diode model of a solar cell

For the purpose of this modeling and performance evaluation of the mentioned cell type, the AZURSPACE triple-junction solar cell is selected given in [19]. It is assumed that the sub-cells are latticed-matched and therefore providing same current unlike [20] where the minimum current of the group is taken. Because, the study presented in [20] is based on Air Mass (AM) greater than zero. With reference to Figure 3, cell current can be obtained using Kirchhoff's current law as

$$I = I_{ph,i} \quad I_{d,i} \quad I_{sh,i} \tag{1}$$

where I is the current of the cell,  $I_{ph,i}$  is the photo-generated current in the sub-cells,  $I_{d,i}$  is the diode current for the sub-cells, and  $I_{shi}$  the current in the shunt branch of each sub-cell, the subscript i = 1, 2, and 3 for the three subcells, respectively. Photo-generated current  $I_{phi}$  is given by

$$I_{ph,i} = \begin{bmatrix} I_{sc} + k_{I_{sc}} (T_c & T_{ref}) \end{bmatrix} \cdot \frac{G}{G_{ref}}$$
(2)

In Equation (2),  $I_{sc}$  is the short-circuit current of the cell when open-circuit voltage equals to zero.  $k_{I_{sc}}$  is the short-circuit temperature coefficient in  $Amp/^{\circ}C$  and it is a very small value for triple-junction cells and its effect is minimal [21].  $T_c$  and  $T_{ref}$  are the operating temperature of the cell, respectively. Reference temperature at standard test conditions (STC) is used as 28°C.  $G_{ref}$  and G are the reference solar irradiance given as  $1367W/m^2$ , AMO, at STC and the actual irradiance falling on the cell area, respectively.

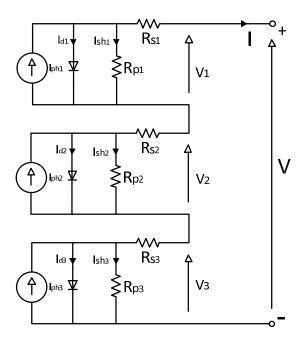


Figure 3. One-diode model of a triple-junction solar cell

$$I_{d,i} = I_{o,i} \cdot \begin{bmatrix} e^{q \cdot \frac{\left(V + A.I.R_{s,i}\right)}{n_i \cdot k_b \cdot T_c}} & 1 \end{bmatrix}$$

$$(3)$$

$$I_{o,i} = I_{rs,i} \cdot T_c^{\left(\frac{3+\gamma i}{2}\right)} \cdot e^{\frac{-q \cdot E_{g,i}(T_c)}{n_i \cdot k_b \cdot T_c}}$$
(4)

The diode current  $I_{d,i}$  and  $I_{o,i}$  are a function of the lumped reverse saturation and recombination currents  $I_{rs,i}$  given as  $K_i$  for the 5-parameter model.  $I_{rs,i}$  is determined usually through measurements given in [11] and [15].  $\gamma_i$  is another ideality constant,  $E_{g,i}(T_c)$  is the band gap and  $n_i, k_b$ , and q are the ideality factor depending on the tunnel junction quality. Boltzmann's constant given by  $1.380658 \times 10^{-23} J/K$  and the charge of electron as  $1.602 \times 10^{-19} C$ , respectively. V is the voltage at the terminal of the cell.  $R_{s,i}$  and A are the series resistances of the sub cells, the effective area of the cell, respectively. From Equation (4), band gap energy  $E_{g,i}(T_c)$  is given by the relation

$$E_{g,i(T_c)} = E_{g,i(0)} \quad \frac{\alpha_i T_c^2}{T_c + \beta_i}$$
 (5)

 $E_{g,i(0)}$  in Equation (5) is the measured band gap obtained at temperature of zero Kelvin.  $\alpha_{,i}$  and  $\beta_i$  are all distinct for the semiconductors and directly related to temperature effect.  $\alpha_{,i}$  is the energy per Kelvin of the material while  $\beta_i$  is a fitting parameter for the temperature. Shunt current indicated as  $I_{sh,i}$  is given in Equation (6)

$$I_{sh,i} = \frac{V + I.A.R_{s,i}}{A.R_{p,i}} \tag{6}$$

where  $R_{p,i}$  is the parallel resistance of the cell and often neglected. Substituting Equations (2), (3), (4), and (6) into equation (1) yields equation (7) known as the output current equation of the cell given as

$$I = I_{ph,i} I_{o,i} \left[ e^{\left(\frac{V+I.A.R_{s,i}}{n.V_t}\right)} 1 \right] \frac{V+I.A.R_{s,i}}{A.R_{p,i}}$$
 (7)

Cell voltage of each sub cell  $V_i$  extracted from Equation (7) by neglecting the parallel resistance  $R_p$  seen in [15] and [20] derived in Equation (8)

$$V_i = \frac{n_i \cdot k \cdot T_c}{q} \cdot \ln\left(\frac{I_{sc,i}}{I_{o,i}} + 1\right) \quad I.A.R_{s,i}$$
(8)

The total cell voltage is the summation of the voltages of the sub cells  $V_i$ 

$$V = \frac{k.T_c}{q} \cdot \left[ n_1 \cdot \ln \left( \frac{I_{SC,1}}{I_{0,1}} + 1 \right) + n_2 \cdot \ln \left( \frac{I_{SC,2}}{I_{0,2}} + 1 \right) + n_3 \cdot \ln \left( \frac{I_{SC,3}}{I_{0,3}} + 1 \right) \right] \quad I.A.R_s(9)$$

Open-circuit voltage  $V_{oc,i}$  of each sub cell is shown in Equation (10) and the total  $V_{oc}$  of the cell is given in Equation (11)

$$V_{oc,i} = \frac{k \cdot T_c}{q} \cdot \left[ n_i \cdot \ln \left( \frac{I_{SC,i}}{I_{o,i}} + 1 \right) \right] \tag{10}$$

$$V_{oc} = \frac{k.T_c}{q} \cdot \left[ n_1 \cdot \ln \left( \frac{I_{SC,1}}{I_{o,1}} + 1 \right) + n_2 \cdot \ln \left( \frac{I_{SC,2}}{I_{o,2}} + 1 \right) + n_3 \cdot \ln \left( \frac{I_{SC,3}}{I_{o,3}} + 1 \right) \right]$$
(11)

Equations (7) and (9) are the output current and voltage equations, in order. Note that

$$R_s = \sum_{i=1}^3 Rs_i \tag{12}$$

Fill factor (FF) is a measurement of qualitative a particular cell

$$FF = \frac{V_{mpp}.I_{mpp}}{V_{oc}.I_{sc}} \tag{13}$$

where  $V_{mpp}$  is the cell voltage at the maximum power point, and  $I_{mpp}$  is the current of the cell. Equation (13) is used to obtain the conversion efficiency  $\eta$  of the cell which is shown in Equation (14)

$$\eta = \frac{FF.V_{oc}.I_{sc}}{G.A} \times 100\% \tag{14}$$

where G is the solar irradiance received by the cell and A is the area of the cell studied in  $m^2$  as in [20] and [22]. Another method for calculating the conversion efficiency is explained in [13].

The designed model is implemented using Equation (1)-(14), and these are normally enough to implement the electrical model of the triple-junction solar cell in a simulation tool.

Parameter	Value	Parameter	Value	Parameter	Value
$E_{g1(0)}$	1.79	$\gamma_1$	1.81	$n_1$	1.89
$E_{g2(0)}$	1.39	$\gamma_2$	1.86	$n_2$	1.59
$E_{g3(0)}$	0.68	γ <sub>3</sub>	1.44	$n_3$	1.43
$K_{i1}$	0.0253 <i>mA</i> /°C	$\alpha_1$	7.5e <sup>-4</sup>	K <sub>1</sub>	$1.86e^{-9}$
$K_{i2}$	0.0005 <i>mA</i> /°C	$\alpha_2$	$5.405e^{-4}$	$K_2$	$2.195e^{-7}$
$K_{i3}$	0.0098 <i>mA</i> /°C	$\alpha_3$	$4.7774e^{-4}$	<i>K</i> <sub>3</sub>	$10.5e^{-9}$
$K_{v1}$	6.93 <i>mV</i> /°C	$R_{S1}$	$0.023\Omega$	$T_{ref}$	298.15k
$K_{v2}$	6.2 <i>mV</i> /°C	$R_{s2}$	$0.0012\Omega$	$G_{ref}$	$1367W/m^2$
$K_{v3}$	5.6 <i>mV</i> /°C	$R_{s3}$	$\Omega 8000.0$	$I_{mpp}$	504.4 <i>mA</i>
$eta_1$	372	$R_{p1}$	16ΜΩ	$V_{mpp}$	2411mV
$eta_2$	204	$R_{p2}$	$4.5M\Omega$	$V_{oc}$	2700mV
$\beta_3$	235	$R_{p3}$	540 <i>K</i> Ω	$I_{sc}$	520.2 <i>mA</i>

**Table 2.** Input values of the fitting parameters necessary to implement the model

The parameter values used in the simulation are obtained from the datasheet of the solar cell [21]. Input values of the fitting parameters necessary to implement the model using the equations are adopted and presented in Table 2.

Most of the literature cited in this paper are stressed the importance of studying the impact of temperature and irradiance changes on a solar cell. Therefore, it is necessary to investigate these phenomena. The cell used for validation of developed model is reported to have 30% conversion efficiency and it is tested at AM0 irradiance spectrum at a temperature of 28°C. In order to study the performance of the cell, model is simulated at the given parameters of the STC. Since the study investigates the performance of a Space grade cell, the temperature range selected is from (  $20\ to\ 100$ )°C and the irradiance is increased from  $200\ to\ 1367\ W/m^2$  in a step of 200.

#### 2.2 Modeling and Control of SEPIC

SEPIC is a very attractive converter topology because of its very good electro-magnetic interference (EMI) profile since its input current is non-pulsating. Another advantage of using SEPIC is that a simple switch gate drive can be used because the switch is connected to the ground of the circuit. That is, complexity in the gate drive circuit reduces since it has same ground node for the input and output. SEPIC has also a very suitable structure for battery storage applications in devices such as laptop and CubeSat [23-25]. Figure 4 represents the schematic of a SEPIC showing all the active and passive elements used for the design of the 3.3V and 5.0V power supplies.

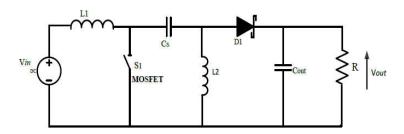


Figure 4. Circuit structure of a SEPIC

SEPIC has two operational states being controlled by the duty cycle "d". Transfer relationship between input and output of an ideal SEPIC as shown in Equation (15) is given by

$$\frac{V_o}{V_{in}} = \frac{d}{1-d} \tag{15}$$

It is modeled using state-space equations in current control mode where the inductor current il1 never falls to zero. The equations of the model for switching periods dTs and  $(1 \ d)Ts$  are obtained. The equations are for the two modes of operations -dTs when S1, is on and  $(1 \ d)Ts$  when the switch S1 is off. Figure 5(a) shows the ON state of the SEPIC while Figure 5(b) shows the OFF state.

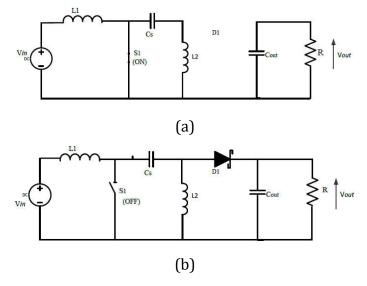


Figure 5. SEPIC states; (a) ON, (b) OFF

State-space model is defined as an equation in the form of [x] = [A][x] + [B][u]

$$[y] = [C][x] + [D][u]$$
(16)
(17)

It is proceed to combine the two states of operation of the converter in to one non-linear equation using the state space averaging (SSA) technique in Equations (12) and (13)

$$[x] = [A_1, d][x] + [B_1, d][u], \text{ for } 0 < t < dT_s$$
(18)

$$[x] = [A_2 \cdot (1 \quad d)][x] + [B_2 \cdot (1 \quad d)][u], \text{ for } 0 < t < (1 \quad d)T_s$$
 (19)

The duty cycle weighed-averaged model can be obtained as follows

$$[x] = [[A_1, d] + [A_2, (1 \quad d)]][x] + [[B_1, d] + [B_2, (1 \quad d)]][u]$$
(20)

$$[V_0] = [[C_1.d] + [C_2.(1 d)]][x] + [[D_1.d] + [D_2.(1 d)]][u] (21)$$

Equations (19) and (20) are combined as averaged large signal model (ALSM) derived in Equation (21).

$$\begin{bmatrix} l_{l1} \\ v_{c1} \\ l_{l2} \\ v_{c2} \end{bmatrix} = \begin{bmatrix} 0 & 0 & \frac{1}{c_1} & 0 & 0 & 0 \\ 0 & \frac{1}{c_1} & \frac{1}{c_2} & 0 & 0 & 0 \\ 0 & 0 & 0 & \frac{1}{Rc_2} & 0 & 0 \\ 0 & 0 & 0 & 0 & 0 & 0 \end{bmatrix} \begin{bmatrix} i_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix} + \begin{bmatrix} 0 \\ 0 \\ 0 \end{bmatrix} \begin{bmatrix} i_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix} + \begin{bmatrix} 0 \\ 0 \end{bmatrix} \begin{bmatrix} v_{in} \end{bmatrix}$$

$$\begin{bmatrix} v_{o} \end{bmatrix} = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} i_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix} + \begin{bmatrix} 0 \\ 0 \end{bmatrix} \begin{bmatrix} v_{in} \end{bmatrix}$$

$$\begin{bmatrix} v_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix} = \begin{bmatrix} \frac{1}{c_1} & 0 & 0 & 0 & 0 \\ 0 & 0 & \frac{1}{c_2} & \frac{1}{c_2} \\ \frac{1}{c_2} & 0 & \frac{1}{c_2} & \frac{1}{Rc_2} \\ \frac{1}{c_2} & 0 & \frac{1}{c_2} & \frac{1}{Rc_2} \\ v_{c2} \end{bmatrix} + \begin{bmatrix} 0 \\ 0 \end{bmatrix} \begin{bmatrix} v_{in} \end{bmatrix}$$

$$[v_o] = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} i_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix} + \begin{bmatrix} 0 \\ 0 \end{bmatrix} [v_{in}]$$

$$[v_o] = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} i_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix} + \begin{bmatrix} 0 \\ 0 \end{bmatrix} [v_{in}]$$

$$(25)$$

$$[v_o] = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} i_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix} + [0][v_{in}]$$
(23)

$$\begin{bmatrix} l_{l1} \\ v_{c1} \\ l_{l2} \\ v_{c2} \end{bmatrix} = \begin{bmatrix} \frac{1}{c_1} & 0 & 0 & 0 \\ 0 & 0 & \frac{-1}{L_2} & \frac{1}{L_2} \\ \frac{-1}{c_2} & 0 & \frac{-1}{c_2} & \frac{-1}{RC_2} \end{bmatrix} \begin{bmatrix} i_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix} + \begin{bmatrix} \frac{1}{L_1} \\ 0 \\ 0 \\ 0 \end{bmatrix} \begin{bmatrix} v_{in} \end{bmatrix}$$
(24)

$$[v_o] = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} l_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix} + \begin{bmatrix} 0 \end{bmatrix} [v_{in}]$$
 (25)

$$A_{1} = \begin{cases} \frac{-1}{L_{1}} & 0 & 0 & 0 \\ 0 & 0 & \frac{1}{C_{1}} & 0 \\ 0 & \frac{-1}{L_{2}} & \frac{-1}{L_{2}} & 0 \\ 0 & 0 & 0 & \frac{-1}{RC_{2}} \\ \frac{-1}{L_{1}} & \frac{-1}{L_{1}} & 0 & \frac{-1}{L_{1}} \\ A_{2} = \begin{cases} \frac{1}{C_{1}} & 0 & 0 & 0 \\ 0 & 0 & \frac{-1}{L_{2}} & \frac{1}{L_{2}} \\ \frac{-1}{C_{2}} & 0 & \frac{-1}{C_{2}} & \frac{-1}{RC_{2}} \\ \frac{1}{L_{1}} \end{cases}$$

$$[B_{1}] = [B_{2}] = \begin{cases} 0 & 0 & 0 \\ 0 & 0 & 0 \end{cases}$$

$$(26)$$

$$A_{2} = \begin{array}{ccccc} \frac{L_{1}}{c_{1}} & L_{1} & L_{1} \\ \frac{1}{c_{1}} & 0 & 0 & 0 \\ 0 & 0 & \frac{-1}{L_{2}} & \frac{1}{L_{2}} \\ \frac{-1}{c_{2}} & 0 & \frac{-1}{c_{2}} & \frac{-1}{RC_{2}} \end{array}$$
 (27)

$$[B_1] = [B_2] = \begin{pmatrix} L_1 \\ 0 \\ 0 \end{pmatrix} \tag{28}$$

$$\begin{bmatrix} C_1 \end{bmatrix} = \begin{bmatrix} C_2 \end{bmatrix} = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix}$$
 (29)  
 $\begin{bmatrix} D_1 \end{bmatrix} = \begin{bmatrix} D_2 \end{bmatrix} = \begin{bmatrix} 0 \end{bmatrix}$  (30)

Equations (30) and (31) are a realization of Equations (19) and (20) by manipulating Equations (25)-(29). ALSM of the converters is stated below.

$$\begin{bmatrix}
l_{l1} \\
v_{c1} \\
l_{l2} \\
v_{c2}
\end{bmatrix} = \begin{bmatrix}
\frac{1}{L_1} & \frac{d-1}{L_1} & 0 & \frac{d-1}{L_1} \\
\frac{1-d}{C_1} & 0 & \frac{d}{C_1} & 0 \\
0 & \frac{-d}{L_2} & \frac{-1}{L_2} & \frac{1-d}{L_2} \\
\frac{1-d}{C_2} & 0 & \frac{d-1}{C_2} & \frac{-1}{RC_2}
\end{bmatrix} \begin{bmatrix}
i_{l1} \\
v_{c1} \\
i_{l2} \\
v_{c2}
\end{bmatrix} + \begin{bmatrix}
i_{l1} \\
v_{l1} \\
v_{l2} \\
v_{l2}
\end{bmatrix} + \begin{bmatrix}
v_{in} \\
0 \\
0
\end{bmatrix} .$$

$$[v_{o}] = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix}
i_{l1} \\
v_{c1} \\
i_{l2} \\
v_{c2}
\end{bmatrix}$$
(32)

$$[v_o] = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} i_{l1} \\ v_{c1} \\ i_{l2} \\ v_{c2} \end{bmatrix}$$
 (32)

To obtain the steady-state and small-signal models of the converter, derivative terms in Equation (30) are set to zero. All other variables are set to steady-state values. Therefore

$$x = 0$$
,  $i_{l1}$ ,  $v_{c1}$ ,  $i_{l2}$ ,  $v_{c2}$ ,  $i_{l2}$ ,  $v_{c1}$ ,  $i_{l2}$ ,  $v_{c2}$ ,  $i_{l2}$ ,  $v_{c2}$ ,  $i_{l2}$ ,  $v_{l0}$ ,  $i_{l2}$ ,  $v_{l0}$ ,  $i_{l2}$ ,  $i_{l2$ 

$$\begin{bmatrix} 0\\0\\0\\0\\0 \end{bmatrix} = \begin{bmatrix} \frac{1}{L_{1}} & \frac{D-1}{L_{1}} & 0 & \frac{D-1}{L_{1}} \\ \frac{1-D}{C_{1}} & 0 & \frac{D}{C_{1}} & 0 \\ 0 & \frac{-D}{L_{2}} & \frac{-1}{L_{2}} & \frac{1-D}{L_{2}} \\ \frac{1-D}{C_{2}} & 0 & \frac{D-1}{C_{2}} & \frac{-1}{RC_{2}} \\ \end{bmatrix} \begin{bmatrix} I_{l1} \\ V_{c1} \\ I_{l2} \\ V_{c2} \end{bmatrix} + \begin{bmatrix} \frac{1}{L_{1}} \\ 0 \\ 0 \end{bmatrix} = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} I_{l1} \\ V_{c1} \\ I_{l2} \\ V_{c2} \end{bmatrix}$$
(33)

$$[V_o] = \begin{bmatrix} 0 & 0 & 0 & 1 \end{bmatrix} \begin{bmatrix} I_{l1} \\ V_{c1} \\ I_{l2} \\ V_{c2} \end{bmatrix}$$
 (34)

Small signal model of the converter is obtained using the ALSM and by applying a perturbation around the steady-state variables of the model where  $x = X + \hat{x}$ 

 $d=D+\hat{d}v_o=V_o+\hat{v}_o$ ,  $v_{in}=V_{in}+\hat{v}_{in}$  are inserted in Equation (32) as given in Equation (34), then, small signal model is extracted by multiplying the steady-state parts and disturbance around the steady-state.

$$\begin{bmatrix} I_{l1} + \iota_{l1} \\ V_{c1} + \nu_{c1} \\ I_{l2} + \iota_{l2} \\ V_{c2} + \nu_{c2} \end{bmatrix} = \begin{bmatrix} \frac{1}{L_1} & \frac{D-1+\hat{d}}{L_1} & 0 & \frac{D-1+\hat{d}}{L_1} \\ \frac{1-D-\hat{d}}{C_1} & 0 & \frac{D+\hat{d}}{C_1} & 0 \\ 0 & \frac{-D-\hat{d}}{L_2} & \frac{-1}{L_2} & \frac{1-D-\hat{d}}{L_2} \\ \frac{1-D-\hat{d}}{C_2} & 0 & \frac{D-1+\hat{d}}{C_2} & \frac{-1}{RC_2} \end{bmatrix} \cdot \begin{bmatrix} I_{l1} + \iota_{l1} \\ V_{c1} + \hat{v}_{c1} \\ I_{l2} + \iota_{l2} \\ V_{c2} + \hat{v}_{c2} \end{bmatrix} + \begin{bmatrix} \frac{1}{L_1} \\ 0 \\ 0 \\ 0 \end{bmatrix} \cdot [V_{in} + \hat{v}_{in}]$$

$$(35)$$

Extracted complete small signal part is described in Equation (35), however, an output current  $\iota_z$  term is added to the model for current control.

$$\begin{bmatrix} l_{l1} \\ \hat{v}_{c1} \\ l_{l2} \\ \hat{v}_{c2} \end{bmatrix} = \begin{bmatrix} \frac{1-D}{c_1} & 0 & \frac{D-1}{L_1} \\ 0 & \frac{D+\hat{d}}{c_1} & 0 \\ 0 & \frac{-D}{L_2} & \frac{1-D}{L_2} \\ \frac{1-D}{c_2} & 0 & \frac{D-1+\hat{d}}{c_2} \\ \frac{1-D}{c_2} & 0 & 0 \end{bmatrix} \begin{bmatrix} \frac{l_{l1}+v_{c2}}{\hat{v}_{c1}} & \frac{1}{L_1} & 0 \\ \frac{l_{l2}+l_{l1}}{c_1} & 0 & 0 \\ \frac{l_{l2}-l_{l1}}{c_2} & 0 & 0 \\ \frac{l_{l2}-l_{l1}}{c_2} & 0 & \frac{-1}{c_2} \end{bmatrix}$$
(36)

From (32), it can be obtained line-to-output transfer function of the plant  $\frac{V_0}{V_{in}}$ while Equation (35) would produce three transfer functions for the controlto-output  $\frac{\widehat{v}_o}{\widehat{d}}$  @  $\widehat{v}_{in} = \iota_z = 0$ . Small signal line-to-output  $\frac{\widehat{v}_o}{\widehat{v}_{in}}$  @  $\widehat{d} = \iota_z = 0$ . Small signal output impedance  $\frac{\hat{v}_0}{\hat{d}}$  evaluated @  $\hat{d} = \hat{v}_{in} = 0$ . Equations (32), (33) and (34) are employed for the controller design.

# 2.2.1 Power Stage Design of SEPIC

There are several methods of design calculations for SEPIC, however, design guides given by Texas Instruments in [26, 27] are adopted and design equations are presented as follows.  $V_{out1} = 3.3V$ ,  $V_{out2} = 5.0V$  (output voltages),  $V_{in,min} = 3.0V$ ,  $V_{in,max} = 4.2$  (input voltage range),  $I_{out1} =$ 2.5Amp,  $I_{out2} = 2.0$ Amp,  $F_{sw} = 1$ MHz (switching frequency), (forward voltage of Schottky diode). Equation (37) and (38) are the formulas for calculating the maximum and minimum duty cycles, respectively.

$$D_{\text{max}} = \frac{V_{\text{out}} + V_{\text{d}}}{V_{\text{in,min}} + V_{\text{out}} + V_{\text{d}}}$$

$$D_{\text{min}} = \frac{V_{\text{out}} + V_{\text{d}}}{V_{\text{in,max}} + V_{\text{out}} + V_{\text{d}}}$$
(38)

$$D_{\min} = \frac{V_{\text{out}} + V_{\text{d}}}{V_{\text{in,max}} + V_{\text{out}} + V_{\text{d}}}$$
(38)

Components/Variables	3.3V Converter	5.0V converter
1 – 1	3.3 μΗ, 4.7μΗ	3.0 μΗ, 4.7μΗ
$L_1 = L_2$	selected	selected
$C_1$	$10\mu F$	$10\mu F$
$C_2$	> 68µF	$> 42\mu F$
$V_d$	0.3 V	0.3 V
$V_{out}$	3.3 V	5.0 <i>V</i>
$V_{in,min}$	3.0 V	3.0 V
$V_{in,max}$	4.2 V	4.2 V
$D_{max}$	0.545	0.638
$D_{min}$	0.461	0.557
$\Delta V_{C1}$	13.6%	12.7%
$I_{out}$	2.5 <i>Amp</i> .	2.0~Amp.
$V_{out,min}$	3.29 V	4.89 <i>V</i>
$V_{out,max}$	3.34 V	5.05 <i>V</i>

Table 3. Circuit parameter values of SEPIC

#### 2.2.2 Controller Design of SEPIC

Figure 6 is the closed-loop control arrangement of the SEPIC with PI controller including the reference and output voltage. It is a feedback controller system used for the converters control.

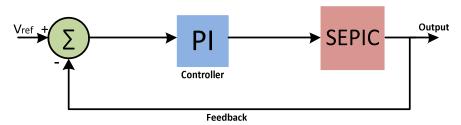


Figure 6. Closed-loop control scheme of the SEPIC

The controllers for 3.3V and 5.0V converters are designed from the state-space model equations. However, both SEPIC and controller transfer functions are fourth order equations, which makes them difficult to implement. SEPICs transfer functions are shown in Equations (39) and (40) for the two converters, respectively.

$$Sepic_{3.3V} = \frac{1.79 \times 10^{9} s^{2} + 3.892 \times 10^{14} s + 1.712 \times 10^{19}}{s^{4} + 4.34 \times 10^{5} s^{3} + 6.029 \times 10^{10} s^{2} + 2.833 \times 10^{15} s + 2.179 \times 10^{19}}$$
(39)

$$Sepic_{5.0V} = \frac{9.404 \times 10^8 s^2 + 2.001 \times 10^{14} s + 1.117 \times 10^{19}}{s^4 + 4.255 \times 10^5 s^3 + 5.688 \times 10^{10} s^2 + 2.471 \times 10^{15} s + 8.844 \times 10^{18}}$$
(40)

Output transfer functions are stated in Equations (41)-(44) for the two converters.

$$G_{dv,3.3V} = \frac{4.853 \times 10^4 s^3 + 4.693 \times 10^{10} s^2 + 8.313 \times 10^{15} s + 3.91 \times 10^{20}}{s^4 + 4.255 \times 10^5 s^3 + 5.802 \times 10^{10} s^2 + 2.714 \times 10^{15} s + 2.088 \times 10^{19}}$$
(41)

$$G_{dvr,3.3V} = \frac{4.768 \times 10^4 s + 3.761 \times 10^{10}}{s^2 + 2.205 \times 10^5 s + 2.009 \times 10^9}$$
(42)

$$G_{dv,5.0V} = \frac{5.302 \times 10^4 s^3 + 4.044 \times 10^{10} s^2 + 6.775 \times 10^{15} s + 3.118 \times 10^{20}}{s^4 + 4.255 \times 10^5 s^3 + 5.688 \times 10^{10} s^2 + 2.471 \times 10^{15} s + 8.844 \times 10^{18}}$$
(43)

$$G_{dvr,5.0V} = \frac{5.243 \times 10^4 s + 3.001 \times 10^{10}}{s^2 + 2.207 \times 10^5 s + 8.516 \times 10^8}$$
(44)

#### 3. SIMULATION RESULTS

### 3.1 Triple-Junction PV Cell Simulation Results

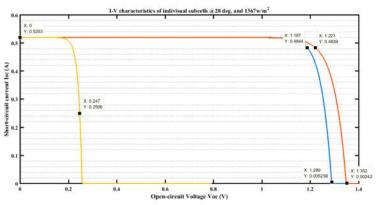
To evaluate the performance of the cell, main variables are considered as  $I_{sc}$ ,  $V_{oc}$ ,  $I_{mpp}$ ,  $V_{mpp}$ ,  $P_{mpp}$ , FF, and efficiency  $\eta$ . In addition, the effect of temperature change on the band gap energy is taken into account since it is a very important part of the model equations. All variables are temperature dependent which can greatly affect the  $V_{mpp}$  and  $P_{mpp}$  as can be seen from the I-V and P-V characteristics curves of the cell.

<b>Parameters</b>	Datasheet values	Simulated values	Percentage Error			
$I_{mpp}(mA)$	504.4	500.2	0.8%			
$V_{mpp}(mV)$	2411	2392	0.7%			
$P_{mpp}(W)$	1.216	1.196	1.644%			
$V_{oc}(mV)$	2700	2659	1.518%			
$I_{sc}(mA)$	520.2	520.3	0.019%			

Table 4. Comparison of datasheet and simulation results at STC

Table 4 is a summary of the performance of the cell at STC. It can be seen from the simulated values that the model has valid results. Simulation results is verified with the given datasheet performance of the cell under same conditions. However, it is noticed that small increment in the short-circuit current is occurred higher than the given value in the datasheet.

I-V and P-V characteristics curves for the individual solar sub-cells at STC extracted from the results are shown in Figures 7 and 8. According to the curves, the "knee" of the curves exists in their maximum points, which are called as "maximum power points" for the individual sub-cells. The lower sub-cell Ge, middle sub-cell GaAs and top cell GaInP produce an open-circuit voltage of 0.2614 V, 1.352 V, and 1.289 V, respectively. The total sum of open-circuit voltages goes up to 2.9024 V while it is 2.7 V in the datasheet, so, percentage error is around 7.5 %. Maximum power points are depicted in Figure 8.



**Figure 7.** I-V characteristics curves of the sub-cells

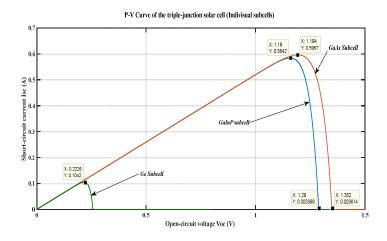


Figure 8. P-V characteristics curves of the sub-cells

Figure 9 is the I-V characteristics curve of the solar cell plotted from the results. The shaded area represents the cell quality. Voltage at maximum power  $V_{mpp}$  is equal to 2.392 V and the current  $I_{mpp}$  stands at 0.5002 A. Maximum power  $P_{mpp}$  can be read from Figure 10 as 1.196 W while the calculated value from the datasheet is equal to 1.2 W. Simulation results show that the designed model is well-done.

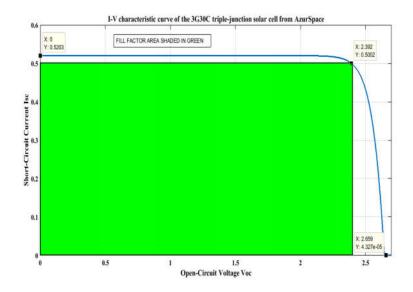


Figure 9. I-V characteristics of the triple-junction solar cell

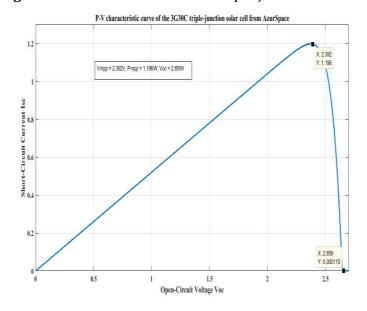


Figure 10. P-V characteristic curve of the Triple-Junction solar cell at STC

FF of the simulated cell (green area in Figure 9) is calculated in accordance with Equation (13)

$$FF = \frac{V_{mpp}.I_{mpp}}{V_{oc}.I_{SC}} \tag{45}$$

FF is calculated to be 0.852 (85.2%). However, calculated FF is 0.8658 (86.58%) and a percentage error is 1.59%. Efficiency calculated from Equation (14) as

$$\eta = \frac{0.852 \times 2.7 \times 0.5202}{1367 \times 0.003018} \times 100\% = 29.0058\%$$

According to the datasheet, average efficiency at  $1367W/m^2$  is 29.5%. But, simulated efficiency from designed model is 29%. It can be confidently said that datasheet values and simulation results are mostly confirmed because the error is only 1.675%. The cell operating temperature has effect on the band gap. As the temperature increase, the band gap energy and open-circuit voltage decreases. The band gap Equation (5) is reproduced as

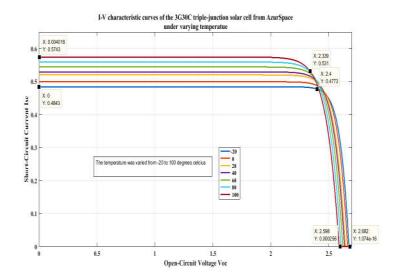
$$E_{g,i(T_c)} = E_{g,i(0)} \quad \frac{\alpha_i T_c^2}{T_c + \beta_i}$$
 (46)

By varying the operating temperature of the cell from (-20 to 100) °C, band gap energy changes from (1.79 to 1.6499) eV in the top cell (GaInP), from (1.39 to 1.2597) eV in the middle cell (GaAs), and from (0.68 to 0.5708) in the bottom sub cell (Ge), in order. Table 5 exhibits the effect of temperature increase on the band gap energy of the triple-junction sub-cells.

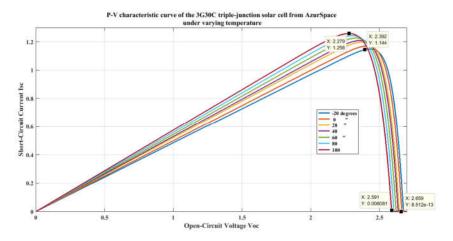
**Table 5.** Change of band bap energy with change in temperature (°C with eV)

Tem	$E_g$ GaInP (1.79)	$E_g GaAs (1.39)$	$E_g Ge(0.68)$	
p				
20	1.7132	1.3143	0.6174	
0	1.7033	1.3055	0.6100	
20	1.6932	1.2966	0.6024	
25	1.6906	1.2944	0.6005	
28	1.6890	1.2930	0.5993	
40	1.6827	1.2876	0.5947	
60	1.6720	1.2784	0.5868	
80	1.6611	1.2691	0.5788	
100	1.6499	1.2597	0.5708	

Figure 11 is the I-V characteristics curve of the cell showing how the parameters  $V_{oc}$  and  $I_{sc}$  vary with increment in operating temperature from (-20 to 100) °C. The  $I_{sc}$  varies from 0.483 to 0.5743 A as the cell operating temperature is increased up to 100 °C from -20°C. On the other hand, the open-circuit voltage is varied from 2.682 V to 2.598 V between -20°C and 100°C.

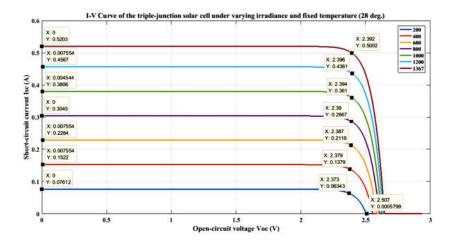


**Figure 11**. I-V characteristics of triple-junction solar cell under fixed irradiance and varying temperature

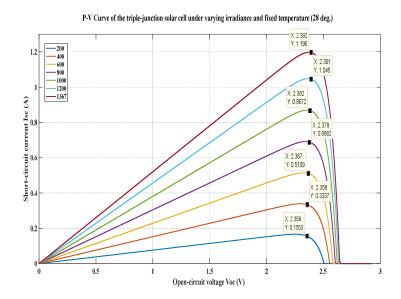


**Figure 12.** P-V characteristics curve of triple-junction cells under varying temperature

In Figure 12, it is presented the plot of the P-V characteristics curve under same conditions of temperature variations. The maximum voltage and maximum power are recorded as 2.306 V and 1.255 W at 100°C while they are recorded as 2.446 V and 1.148 W at -20°C. Figure 13 and 14 demonstrate the I-V and P-V characteristics curves describing the performance of the cell under various irradiance conditions.



**Figure 13.** I-V curve of the cell under fixed temperature of 28°C and varying irradiance



**Figure 14.** P-V curve of the cell under fixed temperature of 28 degrees and varying irradiance

#### 3.2 SEPICs Simulation Results

3.3 V and 5 V SEPIC topologies are simulated and the results are found to be quite satisfactory. Figure 15 and 16 present the output voltage and current curves of the 3.3 V and 5.0 V converters, respectively. All results are within the limits specified in Table 3.

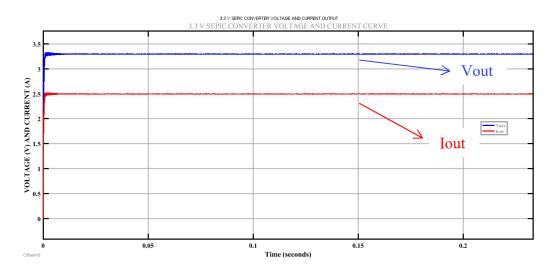


Figure 15. The voltage and current curves of the 3.3V SEPIC

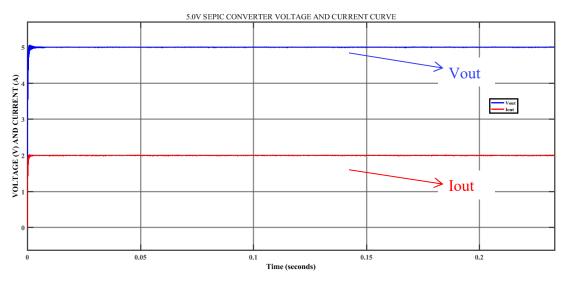


Figure 16. The voltage and current curves of the 5V SEPIC

Controller design for a fourth-order system is a very difficult task; therefore, a suitable way of reducing the models to second-order is employed. The step response of the original fourth-order and the reduced second-order models are compared. The reduced order models are able to represent the original models successfully. Figure 17 shows the step response of the systems both the original and the reduced system of the 3.3V converter. The new step response using the suitable PI coefficients is shown in Figure 18.

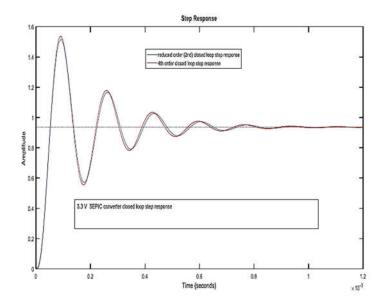


Figure 17. Closed loop original and reduced order step response of the 3.3V SEPIC

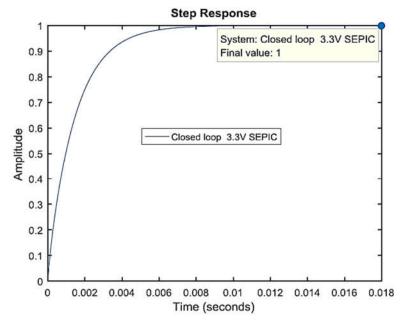
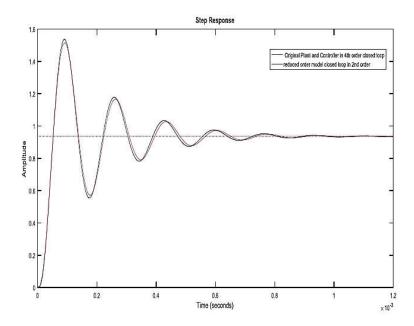
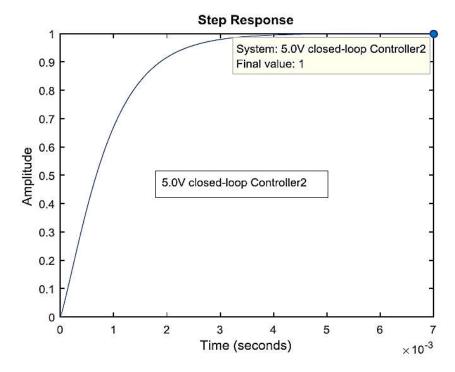


Figure 18. Closed-loop step response of the 3.3V SEPIC

For the 5.0V SEPIC, Figure 19 and 20 show the step response of both the calculated and the tuned PI controller.



**Figure 19.** Tuned step response of the closed loop 5.0V converter



**Figure 20.** Step response of closed-loop 5.0V converter

#### 4. DISCUSSION

Voltage and current output characteristic of the converters are quite promising. In this context, to show the performance of the designed system, a comparison study is carried out in Table 6 with the output voltage profiles of the two famous satellite kits manufacturers called as GOMspace and Endurosat.

Voltage (V)	Designed Converter	Endurosat [28]	GOMspace [29]
3.3	3.294 3.306	3.3 3.45	3.29 3.45
5.0	4.994 5.006	4.88 5.15	4.89 5.05

**Table 6.** Comparison of converter output voltage with those of manufacturers

Comparison in Table 6 gives confidence to accept the result of designed converters modeling, controller design and simulation. However, it is worthy of note that the converter design are performed with ideal components, therefore, it cannot be drawn final conclusions for their superiority over others. Further studies and analysis should be performed.

#### 5. CONCLUSION

An EPS for a conceptual 1U CubeSat mission has been designed by thorough evaluation of performance of the building blocks of the EPS. The functionalities and requirements of the EPS have been clearly spelt out from the onset. Mathematical modeling of the basic elements of the EPS has been provided and design parameters have been also obtained. Triple-junction solar PV cell results have been validated by comparing with the datasheet values. Analysis and performance assessment of designed 3.3 V and 5 V SEPIC have been conducted with good results. Output voltages of the both converters have been compared to the reported similar converters by leading manufacturers of such power supplies. Another important conclusion is that similar CubeSat mission EPSs can be developed without necessarily having to conduct extensive literature survey thanks to this work.

#### REFERENCES

- [1] Cal Poly SLO., **CubeSat Design Specification Rev. 12,** *The CubeSat Program*, California State Polytechnic University (California), 2009.
- [2] Sellers J.J., Astore W.J., Giffen R.B. and Larson W.J., **Understanding Space: an Introduction to Astronautics,** *McGraw Hill (New York)*, 3rd edition, 2000.
- [3] Craig Clark, Alejandro Lopez Mazarias, **Power System Challenges for Small Satellite Missions**, *Proceedings of the 2006 Small Satellites, Systems and Services Symposium*, D. Danesy, Ed. The Netherlands: ESA, 2006.
- [4] Sun C.S. and Juang J.C., **Design and Implementation of a Microsatellite Electric Power Subsystem,** *Journal of Aeronautics, Astronautics and Aviation, Series A,* **44**(2), pp. 67-73, 2012.
- [5] Jacobsen L.E., **Electrical Power System of the NTNU Test Satellite**, *Master Thesis*, Norwegian University of Science and Technology, 2012.
- [6] Nishioka K., Takamoto T., Agui T., Kaneiwa M., Uraoka Y. and Fuyuki T., Evaluation of InGaP/InGaAs/Ge triple-junction solar cell under concentrated light by simulation program with integrated circuit emphasis, Japanese Journal of Applied Physics, 43(3R), 882, 2004.

- [7] Yuya Sakurada, Yasuyuki Ota and Kensuke Nishioka, **Simulation of Temperature Characteristics of InGaP/InGaAs/Ge Triple-Junction Solar Cell under Concentrated Light**, *Journal of Applied Physics*, 50(4S), 04DP13, 2011.
- [8] Dida A.H. and Bekhti M., **Study, modeling and simulation of the electrical characteristic of space satellite solar cells**, 2017 IEEE 6th International Conference on Renewable Energy Research and Applications (ICRERA), pp. 983-987, IEEE, 2017.
- [9] Rezk H. and Hasaneen E.S., A new MATLAB/Simulink model of triple-junction solar cell and MPPT based on artificial neural networks for photovoltaic energy systems, Ain Shams Engineering Journal, 6(3), pp. 873-881, 2015.
- [10] Das N., Al Ghadeer A. and Isla, S., **Modelling and analysis of multi-**junction solar cells to improve the conversion efficiency of
  photovoltaic systems, 2014 Australasian Universities Power
  Engineering Conference (AUPEC), pp. 1-5, IEEE, 2014.
- [11] Hussain A.B., Abdalla A.S., Mukhtar A.S., Elamin M., Alammari R. and Iqbal A., **Modelling and simulation of single-and triple-junction solar cells using MATLAB/SIMULINK**, *International Journal of Ambient Energy*, 38(6), pp. 613-621, 2017.
- [12] Philipps S.P., Guter W., Welser E., Schöne J., Steiner M., Dimroth F. and Bett A.W., **Present status in the development of III–V multi-junction solar cells**, *Next Generation of Photovoltaic*, Berlin, Heidelberg, pp. 1-21, Springer, 2012.
- [13] Bett A.W., Dimroth F., Guter W., Hoheisel R., Oliva E., Philipp, S.P., Schöne J., Siefer G., Steiner M., Wekkeli A. and Welser E., **Highest efficiency multi-junction solar cell for terrestrial and space applications**, *Space*, 25(25.8), pp. 30-6, 2009.
- [14] Yunus Emre Yağan, Kadir Vardar and Mehmet Ali Ebeoğlu, **Modeling** and Simulation of PV Systems, *IOSR Journal of Electrical and Electronics Engineering (IOSR-JEEE)*, 13(2), pp. 1-11, 2018.
- [15] Segev G., Mittelman G. and Kribus A., **Equivalent circuit models for triple-junction concentrator solar cells**, *Solar Energy Materials and Solar Cells*, *98*, pp. 57-65, 2012.
- [16] Thakur M. and Singh B., A MATLAB/Simulink Model of Triple-Junction Solar Cell and MPPT Based on Incremental Conductance Algorithm for PV System, International Journal of Engineering Research and Applications, 5(9), pp. 92-95, 2015.
- [17] Dey B.K., Khan I., Mandal N. and Bhattacharjee A., **Mathematical modelling and characteristic analysis of Solar PV Cell**, 2016 IEEE 7th Annual Information Technology, Electronics and Mobile Communication Conference (IEMCON), pp. 1-5. IEEE, 2016.
- [18] Sarkar M.N.I., **Effect of various model parameters on solar photovoltaic cell simulation: A SPICE analysis**. *Renewables: Wind, Water, and Solar, 3*(1), pp. 13, 2016.

- [19] **3G30C AZURSPACE Triple-Junction Solar Cell**, Available at: http://www.azurspace.com/images/products/0004148-00-01\_DB\_GBK\_80%C2%B5m.pdf (Accessed 21.02.2019)
- [20] Theristis M. and O'Donovan T.S., Electrical-thermal analysis of III-V triple-junction solar cells under variable spectra and ambient temperatures, *Solar Energy*, 118, pp. 533-546, 2015.
- [21] Colasanti S., Nesswetter H., Zimmermann C.G. and Lugli P., **Modeling** and parametric simulation of triple junction solar cell for space application, 2014 IEEE 40th Photovoltaic Specialist Conference (PVSC), pp. 1784-1789, IEEE, 2014.
- [22] Bimenyimana S., Asemota G.N.O. and Lingling L., **Output Power Prediction of Photovoltaic Module Using Nonlinear Autoregressive Neural Network**, *Power*, *31*, 12, 2014.
- [23] Priya S. P., Radhika A., and Vinothini T. D., **MPPT and SEPIC Based Controller Development for Energy Utilisation in CubeSats**, *2012 Annual IEEE India Conference (INDICON)*, pp. 143-148, IEEE, 2012.
- [24] Waghulde D., Kapgate N., Pisal S., Papal S., Gajare T., Rathod B., ... & Phanse A., Simulation, Design and Implementation of Various MPPT Systems for Micro Cube-Satellite Application, 2016 Second International Innovative Applications of Computational Intelligence on Power, Energy and Controls with their Impact on Humanity (CIPECH), pp. 80-84, 2016.
- [25] Li N. Digital control strategies for DC/DC SEPIC converters towards integration, *PhD Thesis*, Lyon, INSA, 2012.
- [26] Zhang, D., **AN-1484 Designing a SEPIC Converter**, *Texas Instruments*, 2006.
- [27] Jeff F., **Designing DC-DC Converters Based on SEPIC Topology,** *Analog Instrumentation Journal, Texas Instruments, Web. 12*, 2016.
- [28] **ENDUROSAT CubeSat Structure**, Available at: https://www.endurosat.com/products/#power-modules. (Accessed 21.02.2019)
- [29] **GOMspace Structure**, Available at: https://gomspace.com/Shop/subsystems/power-supplies/nanopower-p31u.aspx (Accessed 21.02.2019)